

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

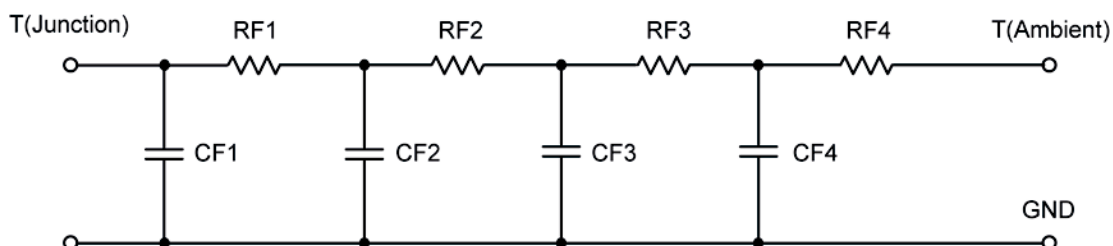
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	13.5510	N/A	6.9236
RT2	4.6916	N/A	1.0702
RT3	19.8626	N/A	6.5044
RT4	41.8404	N/A	6.5396
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	33.5652 m	N/A	12.4807 m
CT2	9.4594 m	N/A	1.8997 m
CT3	131.2610 m	N/A	354.6357 m
CT4	1.7592	N/A	70.1462 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	6.0069	N/A	1.5179
RF2	18.4914	N/A	9.1863
RF3	15.9491	N/A	5.2777
RF4	39.4210	N/A	5.0728
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	4.4507 m	N/A	1.7903 m
CF2	23.2231 m	N/A	8.4123 m
CF3	93.4185 m	N/A	65.8067 m
CF4	1.7142	N/A	284.0581 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

